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January 2015

J111 / J112 / J113 / MMBFJ111 / MMBFJ112 / MMBFJ113 N-Channel Switch

Features

- This device is designed for low level analog switching, sample and hold circuits and chopper stabilized amplifiers.
- Sourced from process 51
- · Source & Drain are interchangeable.



Figure 1. J111 / J112 / J113 Device Package

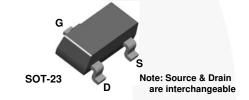


Figure 2. MMBFJ111 / MMBFJ112 / MMBFJ113 Device Package

Ordering Information

Part Number	Part Number Top Mark		Packing Method	
J111	J111 TO-92 3L		Bulk	
J111_D26Z	J111 TO-92 3L		Tape and Reel	
J111_D74Z	J111	TO-92 3L	Ammo	
J112	J112 J112		Bulk	
J112_D26Z	J112_D26Z J112		Tape and Reel	
J112_D27Z	J112	TO-92 3L	Tape and Reel	
J112_D74Z	J112	TO-92 3L	Ammo	
J113	J113 J113		Bulk	
J113_D74Z	J113_D74Z J113		Ammo	
J113_D75Z	J113	TO-92 3L	Ammo	
MMBFJ111	MMBFJ111 6P		Tape and Reel	
MMBFJ112	MMBFJ112 6R		Tape and Reel	
MMBFJ113	MMBFJ113 6S		Tape and Reel	

Absolute Maximum Ratings(1), (2)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{DG}	Drain-Gate Voltage	35	V
V_{GS}	Gate-Source Voltage	-35	V
I _{GF}	Forward Gate Current	50	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 to 150	°C

Notes:

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

Thermal Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

		Ma		
Symbol	Parameter	J111 / J112 / J113 ⁽³⁾	MMBFJ111 / MMBFJ112 / MMBFJ113 ⁽⁴⁾	Unit
P _D	Total Device Dissipation	625	350	mW
r D	Derate Above 25°C	5.0	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case 125		°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient 200 357			°C/W

Notes:

- 3. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.
- 4. Device mounted on FR-4 PCB 36mm × 18mm × 1.5mm; mounting pad for the collector lead minimum 6cm².

Electrical Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

urce Breakdown Voltage verse Current	$I_G = -1.0 \mu A, V_{DS} = 0$			•	
verse Current			-35		V
	$V_{GS} = -15 \text{ V}, V_{DS} = 0$			-1.0	nA
		111	-3.0	-10.0	
urce Cut-Off Voltage	$V_{DS} = 15 \text{ V}, I_D = 1.0 \mu\text{A}$	112	-1.0	-5.0	V
		113	-0.5	-3.0	1
utoff Leakage Current	$V_{DS} = 5.0 \text{ V}, V_{GS} = -10 \text{ V}$			1.0	nA
			•	•	•
		111	20		
te Voltage Drain Current ⁽⁵⁾	$V_{DS} = 15 \text{ V}, V_{GS} = 0$	112	5.0		mA
		113	2.0		1
		111		30	
ource On Resistance	$V_{DS} \le 0.1 \text{ V}, V_{GS} = 0$	112		50	Ω
		113		100	
cteristics		1		•	
ate &Source-Gate On ance	$V_{DS} = 0, V_{GS} = 0, f = 1.0 M$	Hz		28	pF
ate Off Capacitance	$V_{DS} = 0$, $V_{GS} = -10$ V, $f = 1$.	0 MHz		5.0	pF
Gate Off Capacitance	$V_{DS} = 0$, $V_{GS} = -10$ V, $f = 1$.	0 MHz		5.0	pF
	te Voltage Drain Current (5) burce On Resistance cteristics ate &Source-Gate On ance ate Off Capacitance	te Voltage Drain Current $V_{DS} = 5.0 \text{ V}, V_{GS} = -10 \text{ V}$ te Voltage Drain Current $V_{DS} = 15 \text{ V}, V_{GS} = 0$ burce On Resistance $V_{DS} \le 0.1 \text{ V}, V_{GS} = 0$ cteristics ate &Source-Gate On ance $V_{DS} = 0, V_{GS} = 0, f = 1.0 \text{ M}$ ate Off Capacitance $V_{DS} = 0, V_{GS} = -10 \text{ V}, f = 1.0 \text{ M}$	to the Voltage Drain Current $V_{DS} = 5.0 \text{ V}, V_{GS} = -10 \text{ V}$ the Voltage Drain Current $V_{DS} = 15 \text{ V}, V_{GS} = 0$ The Voltage Drain Current	te Voltage Drain Current ⁽⁵⁾ $V_{DS} = 5.0 \text{ V}, V_{GS} = -10 \text{ V}$ te Voltage Drain Current ⁽⁵⁾ $V_{DS} = 15 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 15 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 15 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 15 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 15 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 15 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 111 \text{ V}$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to voltage Drain Current ⁽⁵⁾ $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ to volt	te Voltage Drain Current $V_{DS} = 5.0 \text{ V}, V_{GS} = -10 \text{ V}$ te Voltage Drain Current $V_{DS} = 15 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 15 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 15 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 15 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 15 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 15 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 15 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 0.1 \text{ V}, V_{GS} = 0$ The Voltage Drain Current $V_{DS} = 0.1 \text{ V}, V_{GS} = 0.1 \text{ V},$

Note:

5. Pulse test: pulse width \leq 300 μ s, duty cycle \leq 2%.

Typical Performance Characteristics

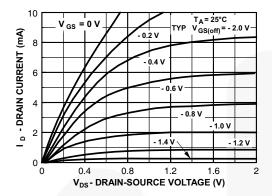


Figure 3. Common Drain-Source

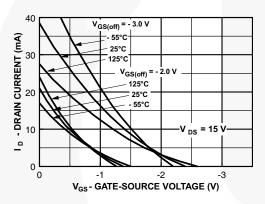


Figure 5. Transfer Characteristics

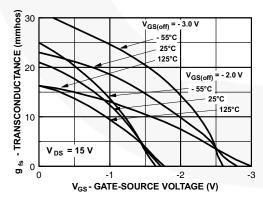


Figure 7. Transfer Characteristics

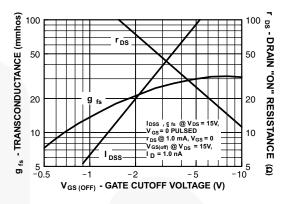


Figure 4. Parameter Interactions

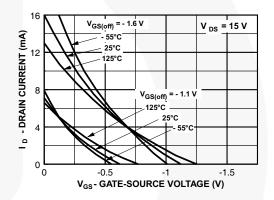


Figure 6. Transfer Characteristics

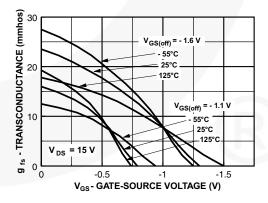


Figure 8. Transfer Characteristics

Typical Performance Characteristics (Continued)

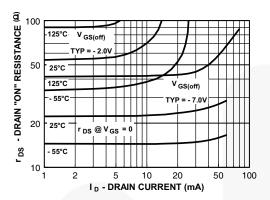


Figure 9. On Resistance vs. Drain Current

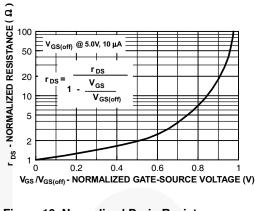


Figure 10. Normalized Drain Resistance vs.

Bias Voltage

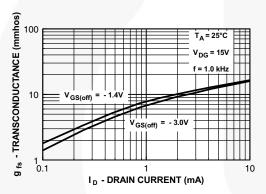


Figure 11. Transconductance vs. Drain Current

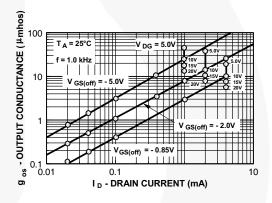


Figure 12. Output Conductance vs. Drain Current

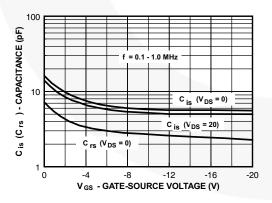


Figure 13. Capacitance vs. Voltage

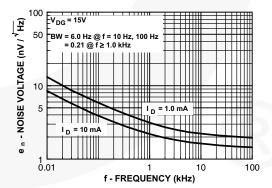


Figure 14. Noise Voltage vs. Frequency

Typical Performance Characteristics (Continued)

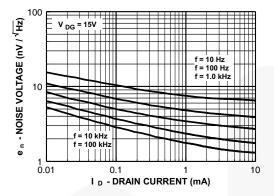


Figure 15. Noise Voltage vs. Current

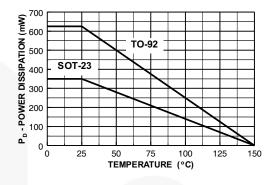


Figure 16. Power Dissipation vs.
Ambient Temperature

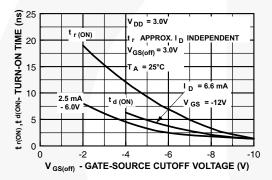


Figure 17. Switching Turn-On Time vs.
Gate-Source Voltage

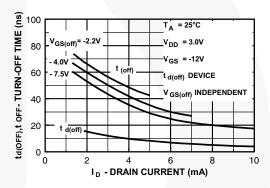
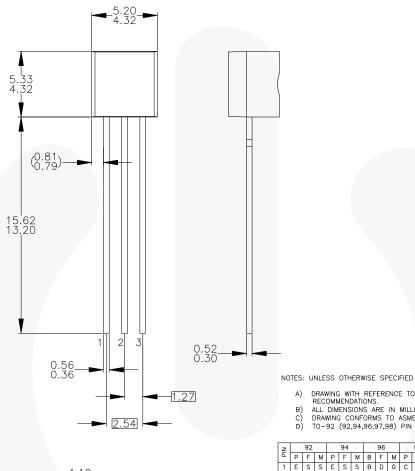


Figure 18. Switching Turn-Off Time vs. Drain Current

Physical Dimensions



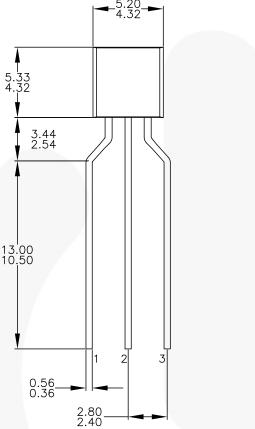
DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.
ALL DIMENSIONS ARE IN MILLIMETERS.
DRAWING CONFORMS TO ASME Y14.5M-1994.
TO-92 (92,94,96,97,98) PIN CONFIGURATION:

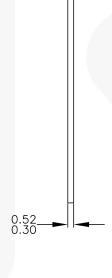
P F M P F M B F M P F M P F M _4.19 _3.05 LEGEND: 2 3

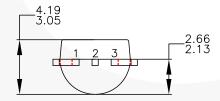
P - BIPOLAR F - JFET M - DMOS E - EMITTER B - BASE C - COLLECTOR E) FOR PACKAGE 92, 94, 96, 97 AND 98:
PIN CONFIGURATION DRAIN "D" AND SOURCE "S"
ARE INTERCHANGEAGLE AT JFET "F" OPTION.
F) DRAWING FILENAME: MKT—ZAO3DREV3.

Figure 19. 3-Lead, TO-92, JEDEC TO-92 Compliant Straight Lead Configuration, Bulk Type

Physical Dimensions (Continued)







NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING CONFORMS TO JEDEC MS-013, VARIATION AC. ALL DIMENSIONS ARE IN MILLIMETERS. DRAWING CONFORMS TO ASME Y14.5M-2009. DRAWING FILENAME: MKT-ZAO3FREV3. FAIRCHILD SEMICONDUCTOR.

Figure 20. 3-Lead, TO-92, Molded, 0.2 In Line Spacing Lead Form, Ammo, Tape and Reel Type

Physical Dimensions (Continued) 0.95 2.92±0.20 3 1.40 1.30+0.20 2.20 2 0.60 0.37 (0.29) -0.95 ⊕ | 0.20 M | A | B 1.00 1.90 1.90 LAND PATTERN RECOMMENDATION SEE DETAIL A -1.20 MAX 0.10 (0.93) ○ 0.10 ○ C С 2.40±0.30 NOTES: UNLESS OTHERWISE SPECIFIED **GAGE PLANE** A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H. B) ALL DIMENSIONS ARE IN MILLIMETERS. 0.23 C) DIMENSIONS ARE INCLUSIVE OF BURRS, 0.25 MOLD FLASH AND TIE BAR EXTRUSIONS. D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 1994. 0.20 MIN SEATING E) DRAWING FILE NAME: MA03DREV10 **PLANE** (0.55)**DETAIL A** SCALE: 2X

Figure 21. 3-LEAD, SOT23, JEDEC TO-236, LOW PROFILE



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Definition of Terms

Datasheet Identification	Product Status	Definition
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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

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